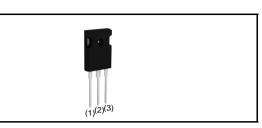


SCT4036DEHR

Automotive Grade N-channel SiC power MOSFET

V _{DSS}	750V
R _{DS(on)} (Typ.)	36mΩ
I_{D}^{*1}	42A
P _D	136W

●Outline TO-247N



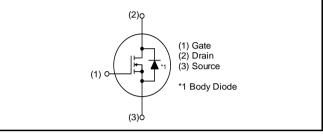
Features

- 1) Qualified to AEC-Q101
- 2) Low on-resistance
- 3) Fast switching speed
- 4) Fast reverse recovery
- 5) Easy to parallel
- 6) Simple to drive
- 7) Pb-free lead plating ; RoHS compliant

Application

- Automobile
- Switch mode power supplies

●Inner circuit



Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT4036DE

●Absolute maximum ratings (T_{vj} = 25°C unless otherwise specified)

Parameter			Symbol	Value	Unit
Drain - source voltage		V _{DSS}	750	V	
Continuous drain		$T_c = 25^{\circ}C$	*1	42	Α
and source current	$V_{GS} = V_{GS_{on}}$	$T_c = 100^{\circ}C$	۰ ا _D , I _S ^{*1}	29	Α
Pulsed drain current	$V_{GS} = V_{GS_{on}}$	$T_c = 25^{\circ}C$	I _{D,pulse} *2	93	Α
Body diode pulsed forwa	ard current	$T_c = 25^{\circ}C$	*1,*3 I _{S,pulse}	42	А
Body diode surge forward current		$V_{GS} = 0 V$	I _{S,pulse} *1,*4	93	Α
Gate - source voltage (DC)		V _{GSS_DC}	-4 to +21	V	
Gate - source surge vol	tage (t _{surge} < 300)ns)	V_{GSS_surge} *5	-4 to +23	V
Recommended turn-on gate - source drive voltage		V _{GS_on} *6	+15 to +18	V	
Recommended turn-off gate - source drive voltage		V _{GS_off}	0	V	
Virtual junction temperature		T _{vj}	175	°C	
Range of storage temperature		T _{stg}	-40 to +175	°C	

•Electrical characteristics ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

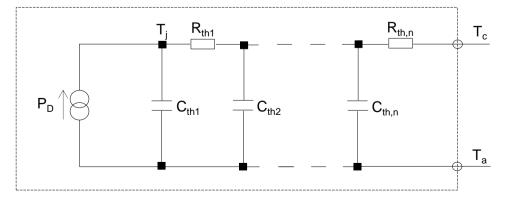
Deremeter	Cumphal	Conditiona	Values			L locit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Drain - Source breakdown	V	$V_{GS} = 0 V, I_D = 7mA$				V	
voltage	V _{(BR)DSS}	T _{vj} = 25°C	750	-	-	V	
		$V_{GS} = 0 V, V_{DS} = 750V$					
Zero Gate voltage Drain current	I _{DSS}	T _{vj} = 25°C	-	1	80	μA	
		T _{vj} = 150°C	-	10	-		
Gate - Source leakage current	I _{GSS+}	$V_{GS} = +21V$, $V_{DS} = 0V$	-	-	100	nA	
Gate - Source leakage current		$V_{GS} = -4V$, $V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	$V_{GS(th)}{}^{*7}$	$V_{DS} = 10V, I_{D} = 11.1mA$	2.8	-	4.8	V	
		$V_{GS} = 18V, I_{D} = 21A$					
Static Drain - Source on - state resistance	${\sf R}_{\sf DS(on)}$ *8	T _{vj} = 25°C	-	36	47	mΩ	
		T _{vj} = 150°C	-	62	-		
Gate input resistance	R_G	f = 1MHz, open drain	-	5	-	Ω	

Thermal resistance

Parameter	Symbol	Values			Unit
	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	${\sf R_{thJC}}^{*9}$	-	0.82	1.1	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	1.1 ×10 ⁻¹		C _{th1}	9.1 ×10 ⁻⁴	
R _{th2}	3.9 ×10 ⁻¹	K/W	C _{th2}	4.2 ×10 ⁻³	Ws/K
R _{th3}	3.5 ×10 ⁻¹		C _{th3}	8.0 ×10 ⁻²	





•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

Demonster	Currente e l	Conditions		11-11			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Transconductance	g _{fs} *8	$V_{DS} = 10V, I_{D} = 21A$	-	10	-	S	
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	1794	-		
Output capacitance	C _{oss}	V _{DS} = 500V	-	98	-	pF	
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	8	-		
Effective output capacitance, energy related	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 500V	-	127	-	pF	
Total Gate charge	Q _g *8	$V_{DS} = 500V$ $I_{D} = 21A$	-	72	-		
Gate - Source charge	Q _{gs} *8	$V_{GS} = 18V$	-	16	-	nC	
Gate - Drain charge	Q _{gd} *8	*8 d See Fig. 1-1, 1-2.		25	-		
Turn - on delay time	t _{d(on)} *8	$V_{DS} = 500V$ $I_{D} = 21A$	-	13	-		
Rise time	t _r *8	V _{GS} = +18V / 0V	-	22	-	ns	
Turn - off delay time	t _{d(off)} *8	$R_G = 0\Omega, L = 250\mu H$ E _{on} includes diode	-	28	-	115	
Fall time	t _f *8	reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF	-	11	-		
Turn - on switching loss	E _{on} *8	See Fig. 2-1, 2-2, 2-3.	-	450	-	μJ	
Turn - off switching loss	E _{off} *8		-	8	-	μυ	
Short-circuit	′ t _{sc} ^{*10}	V _{DS} ≤ 400V V _{DS,peak} ≤ 750V	-	12.0	-	μs	
withstand time $V_{GS(on)} = +18$		$T_{vj(start)} = 25^{\circ}C$ $R_{G} = 2.2\Omega$	-	11.5	-	μs	



●Body diode electrical characteristics (Source-Drain) (T_{vj} = 25°C unless otherwise specified)

Doromotor	Symbol Conditions		Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Onit	
Forward voltage	V_{SD}^{*8}	$V_{GS} = 0V, I_S = 21A$	-	3.3	-	V	
Reverse recovery time	t _{rr} *8	$I_F = 21A$ $V_R = 500V$	-	32	-	ns	
Reverse recovery charge	Q _{rr} *8	di/dt = 2500A/µs	-	170	-	nC	
Peak reverse recovery current	I _{rrm} *8	$L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF See Fig. 3-1, 3-2.	-	11	-	A	

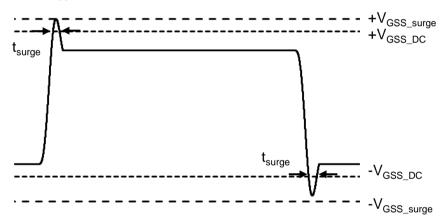
*1 Limited by maximum T_{vi} and for Max. R_{thJC} .

*2 Pulse width and duty cycle are limited by $T_{vj,max}$.

*3 Only for body-diode, Repetitive pulse, PW \leq 1.5µs, Duty cycle \leq 5%

*4 When used as a protective function, PW \leq 10µs

*5 Example of acceptable V_{GS} waveform



- *6 Please be advised not to use SiC-MOSFETs with V_{GS} below 10V as doing so may cause thermal runaway.
- *7 Tested after applying V_{GS} = 21V for 100ms.

*8 Pulsed

*9 Measured conformable to JESD51-14.

See the application note "rthjc_measurement_and_usage_an-e.pdf". Link

 ${\tt URL: https://fscdn.rohm.com/en/products/databook/applinote/discrete/common/rthjc_measurement_and_usage_an-e.pdf}$

*10 Single pulsed.



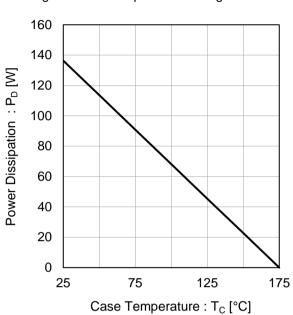
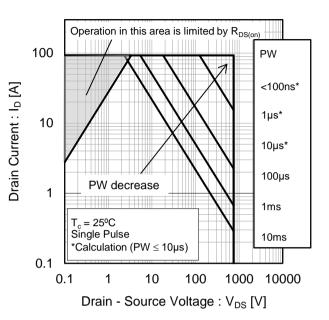
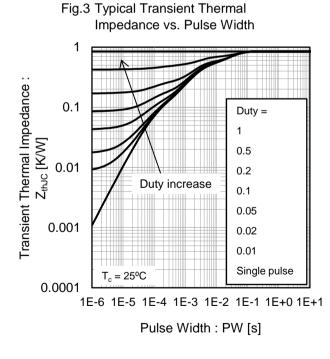


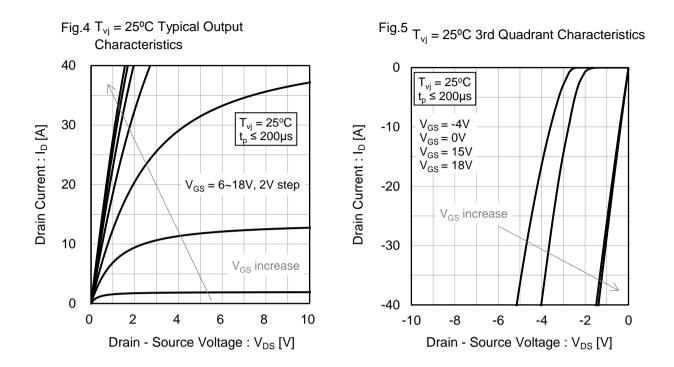
Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area

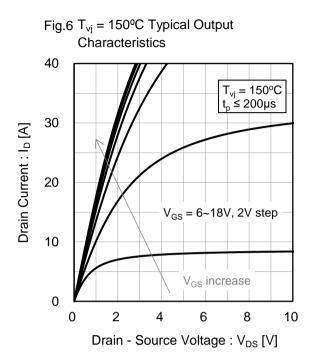


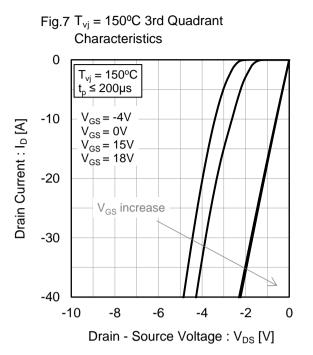


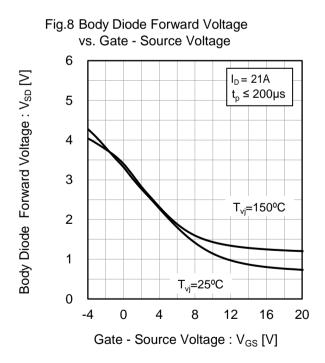












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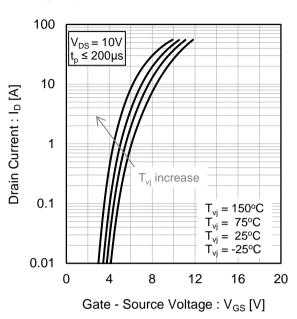
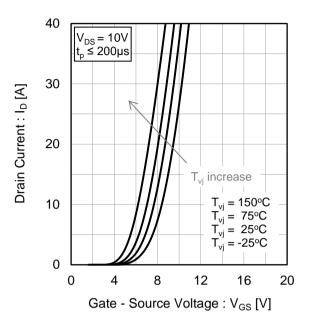


Fig.9 Typical Transfer Characteristics (I)

Fig.10 Typical Transfer Characteristics (II)



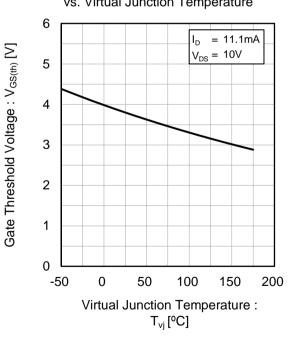


Fig.12 Transconductance vs. Drain Current

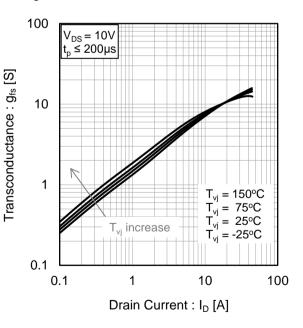
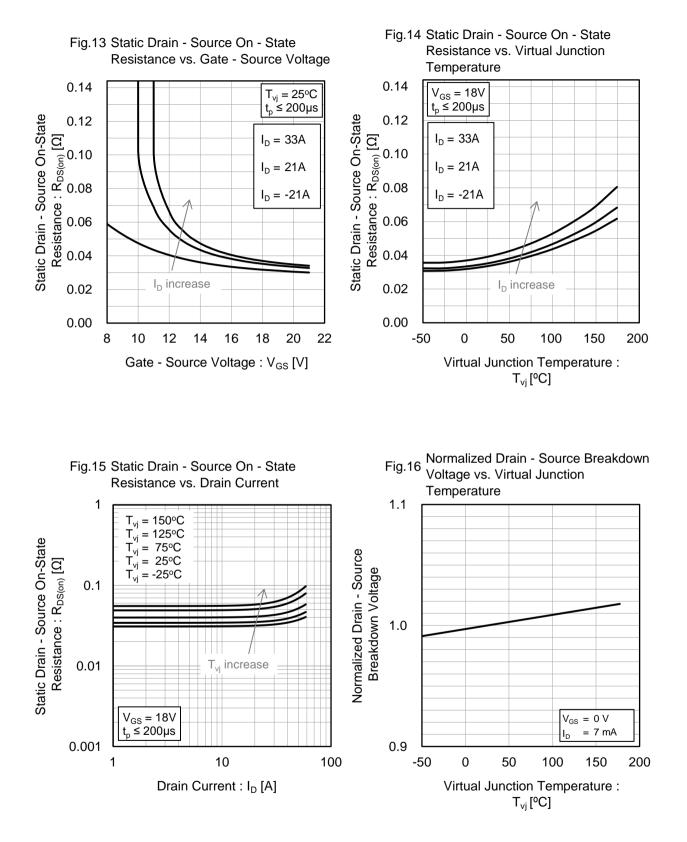


Fig.11 Gate Threshold Voltage vs. Virtual Junction Temperature



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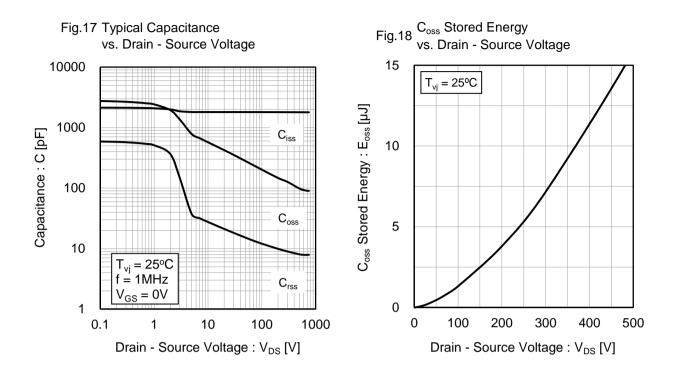
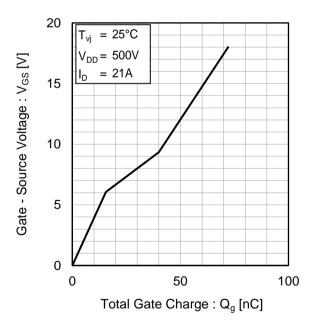
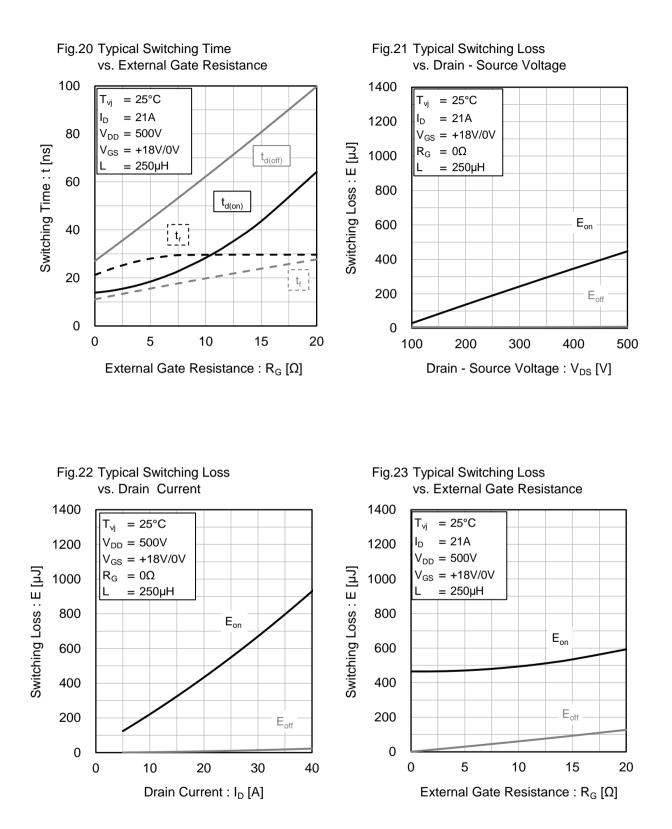


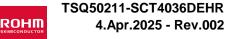
Fig.19 Dynamic Input Characteristics







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Measurement circuits and waveforms

Fig.1-1 Gate Charge Measurement Circuit

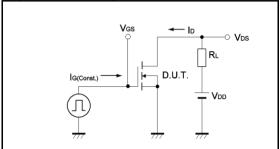


Fig.2-1 Switching Characteristics Measurement Circuit

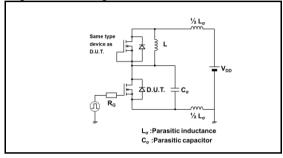


Fig.2-3 Waveforms for Switching Energy Loss

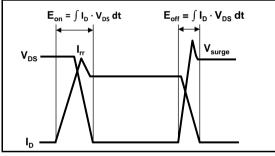


Fig.3-1 Reverse Recovery Time Measurement Circuit

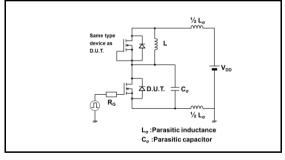
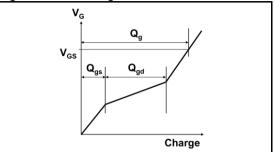


Fig.1-2 Gate Charge Waveform





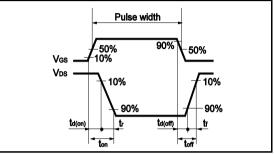
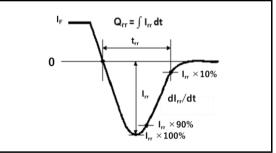


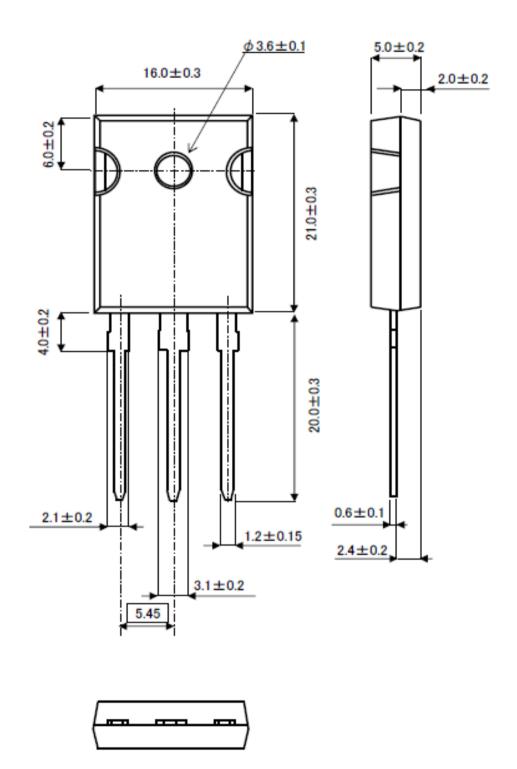
Fig.3-2 Reverse Recovery Waveform





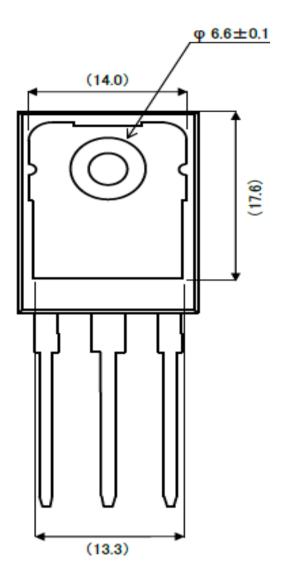


• Package Dimensions



Unit: mm





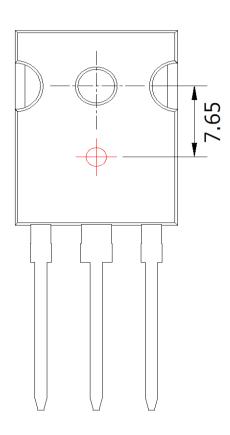
Unit: mm





Die Bonding Layout





•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm





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